2SC5034

Silicon NPN triple diffusion planar type

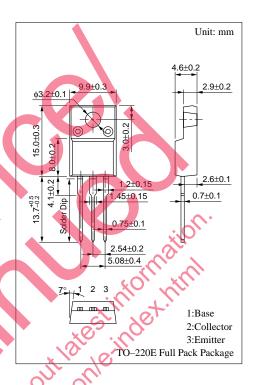
For high breakdown voltage high-speed switching

Features

- ullet High collector to emitter V_{CEO}
- High-speed switching
- Full-pack package with outstanding insulation, which can be installed to the heat sink with one screw

Absolute Maximum Ratings (T_C=25°C)

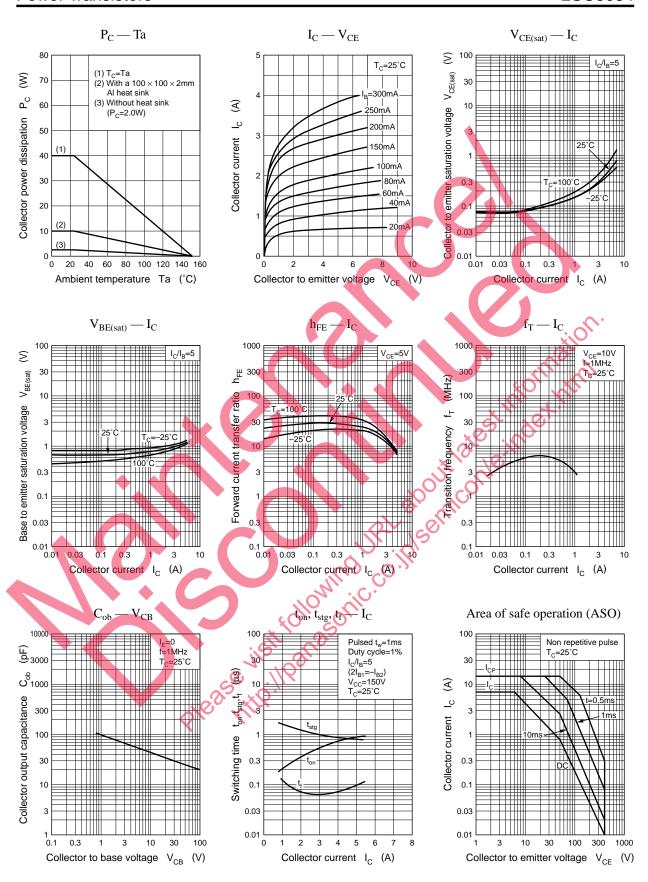
Parameter	Symbol	Ratings	Unit	
Collector to base voltage	V _{CBO}	500	V	
Collector to amitter violes on	V _{CES}	500	V	
Collector to emitter voltage	V _{CEO}	400	V	
Emitter to base voltage	Emitter to base voltage V _{EBO}		V	
Peak collector current	I_{CP}	15	A	
Collector current	I_{C}	7	A	
Base current	I_{B}	3	A	
Collector power T _C =25°C		35	W	
dissipation Ta=25°C	Pc	2.0	W	
Junction temperature T _j		150	°C	
Storage temperature	T _{stg}	-55 to +150	°C	
			201	



Electrical Characteristics (T_C=25°C)

Parameter	Symbol	Conditions	min	typ	max	Unit
Collector cutoff current	I_{CBO}	$V_{\rm CB} = 500 V, I_{\rm E} = 0$			100	μА
Emitter cutoff current	I _{EBO}	$V_{EB} = 5V, I_C = 0$			100	μА
Collector to emitter voltage	V _{CEO}	$I_{\rm O} = 10$ mA, $I_{\rm B} = 0$	400			V
Forward current transfer ratio	h _{EE} i	$V_{\rm CE} = 5 \text{V}, I_{\rm C} = 0.1 \text{A}$	10			
	h _{FE2}	$V_{CE} = 5V, I_{C} = 3A$	8			
Collector to emitter saturation voltage	V _{CE(sat)}	$I_C = 3A, I_B = 0.6A$			1.0	V
Base to emitter saturation voltage	V _{BE(sat)}	$I_C = 3A, I_B = 0.6A$			1.5	V
Transition frequency	f_T	$V_{CE} = 10V, I_{C} = 0.5A, f = 1MHz$		10		MHz
Turn-on time	t _{on}	1 24 1 064 1 124			1.0	μs
Storage time	t _{stg}	$I_C = 3A$, $I_{B1} = 0.6A$, $I_{B2} = -1.2A$,			2.0	μs
Fall time	$t_{\rm f}$	$V_{CC} = 150V$			0.3	μs

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2 Panasonic

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Area of safe operation, reverse bias ASO Reverse bias ASO measuring circuit 000 L coil $\begin{array}{l} {\rm L_{coil}}{\rm =}200\mu {\rm H} \\ {\rm I_{C}}{\rm /I_{B}}{\rm =}5 \\ {\rm (I_{B1}}{\rm =}{\rm -I_{B2}}) \\ {\rm T_{C}}{\rm =}25^{\circ}{\rm C} \end{array}$ 14 T.U.T 3 12 Collector current I_C 10 V_{CC} T . Vclamp 100 200 300 400 500 600 700 800 Please visit following co. in service on the service of the servic Collector to emitter voltage V_{CE} (V) (1) Without heat sink (2) With a $100 \times 100 \times 2$ mm Al heat sink Thermal resistance R_{th}(t) (°C/W)

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